

SANYO Semiconductors DATA SHEET

2SK3283 N-Channel Silicon MOSFET Load Switching Applications

Features

- · Low ON-resistance.
- · 4V drive.

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		30	V
Gate-to-Source Voltage	VGSS		±20	V
Drain Current (DC)	ID		15	Α
Drain Current (Pulse)	IDP	PW≤10μs, duty cycle≤1%	45	Α
Allowable Power Dissipation	Do		1	W
	PD	Tc=25°C	20	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			1.1
			min	typ	max	Unit
Drain-to-Source Breakdown Voltage	V(BR)DSS	I _D =1mA, V _G S=0	30			V
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =30V, V _{GS} =0			1	μΑ
Gate-to-Source Leakage Current	IGSS	VGS=±16V, VDS=0			±10	μΑ
Cutoff Voltage	VGS(off)	V _{DS} =10V, I _D =1mA	1.0		2.4	V
Forward Transfer Admittance	yfs	V _{DS} =10V, I _D =10A	11.2	16		S
Static Drain-to-Source On-State Resistance	RDS(on) 1	ID=10A, VGS=10V		17	23	mΩ
	R _{DS} (on) 2	I _D =4A, V _G S=4V		25	35	mΩ
Input Capacitance	Ciss	V _{DS} =10V, f=1MHz		1550		pF
Output Capacitance	Coss	V _{DS} =10V, f=1MHz		350		pF
Reverse Transfer Capacitance	Crss	V _{DS} =10V, f=1MHz		220		pF

Marking: K3283 Continued on next page.

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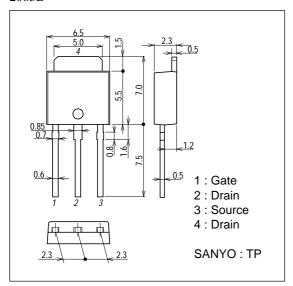
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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	O III
Turn-ON Delay Time	td(on)	See specified Test Circuit.		12		ns
Rise Time	t _r	See specified Test Circuit.		300		ns
Turn-OFF Delay Time	td(off)	See specified Test Circuit.		105		ns
Fall Time	tf	See specified Test Circuit.		100		ns
Total Gate Charge	Qg	V _{DS} =10V, V _{GS} =10V, I _D =15A		40		nC
Gate-to-Source Charge	Qgs	VDS=10V, VGS=10V, ID=15A		5		nC
Gate-to-Drain "Miller" Charge	Qgd	V _{DS} =10V, V _{GS} =10V, I _D =15A		7		nC
Diode Forward Voltage	V _{SD}	I _S =15A, V _{GS} =0		0.92	1.2	V

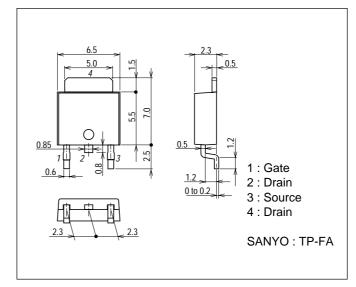
Package Dimensions

unit : mm 2083B

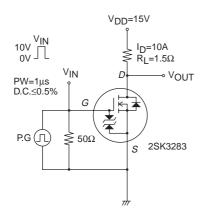


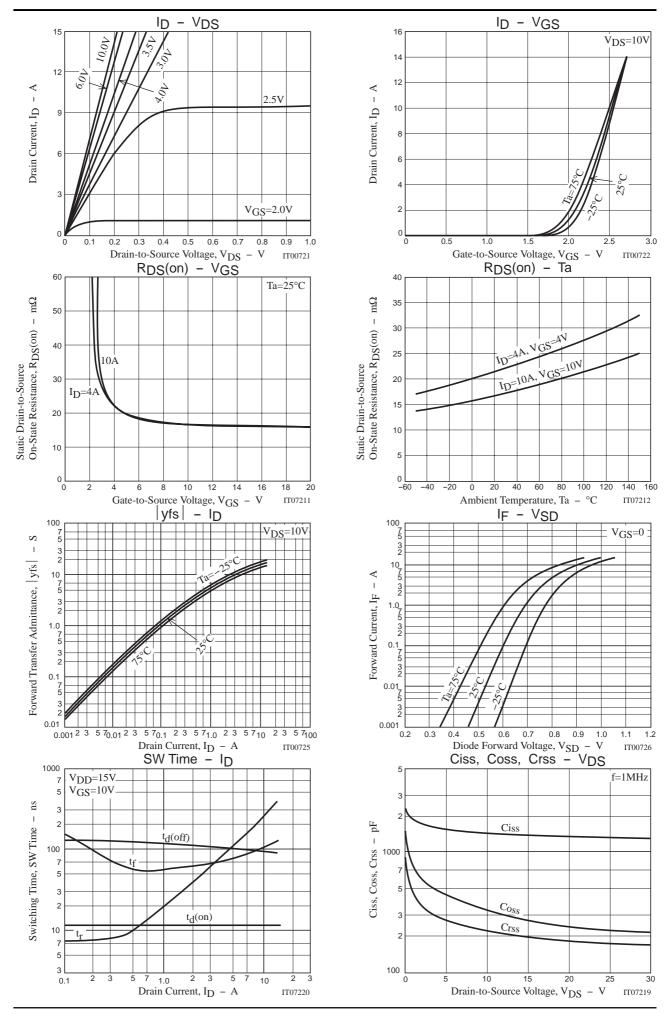
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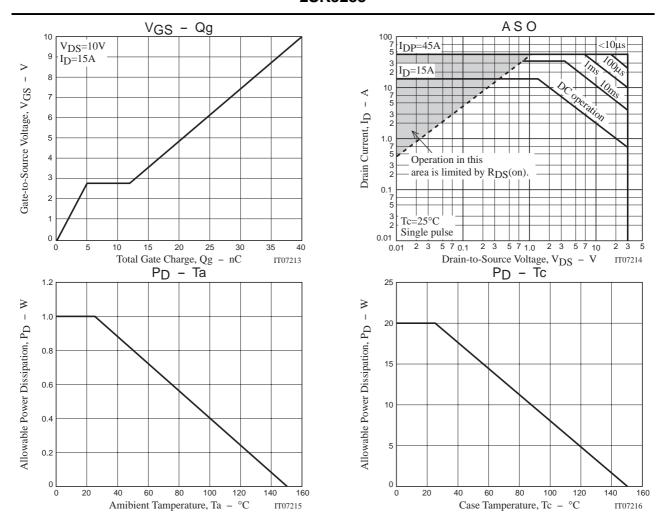
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Switching Time Test Circuit







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